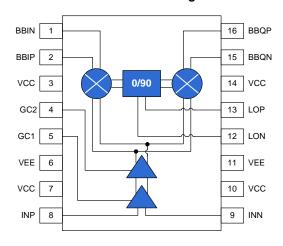


Product Description

The Stanford Microdevices' SRF-2016 is a multipurpose demodulator RFIC capable of both quadrature demodulation or direct IF output. This device features switchable gain control, high input P1dB, and excellent I/Q amplitude and phase balance.

The SRF-2016 uses silicon germanium device technology to yield a highly integrated RFIC for use in a variety of system applications. Use of this integrated device over standard discrete implementations can result in lower component count, less PCB space and higher transceiver card yields.

Functional Block Diagram



Advanced Data Sheet

SRF-2016

200 - 600 MHz Silicon Germanium IF Receiver



16 pin TSSOP with Exposed Pad Package Body: 0.20 x 0.17 x 0.04 (inches) 5.0 x 4.4 x 1.0 (mm)

Product Features

- Buffered IF OUT available through I axis
- Gain control in 20dB steps
- Excellent I/Q amplitude and phase balance
- High input P1dB

Applications

- Digital and spread spectrum communication systems
- Cellular, PCS, DCS, 3G transceivers
- ISM band transceivers
- **FWA** receiver IF sections

Key Specifications

Parameters	Test Conditions (V _{CC} =5.0V, I=150mA, T=25°C)	Unit	Min.	Тур.	Max.
IF/LO Frequency Range		MHz	200	240 to 440	600
Conversion Gain		dB		-5/+15/+35	
Input P1dB		dBm		+10/-10/-30	
I/Q Output Frequency Range		MHz	DC		500
I/Q Output Amplitude Balance		dB	-0.2		0.2
I/Q Output Phase Balance		deg	-2		2

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Absolute Maximum Ratings

Advanced Data Sheet

SRF-2016 SiGe IF Receiver

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Parameters	Value	Unit						
Supply Voltage	6.0	V_{DC}						
LO Input	+10	dBm						
IF Input	+10	dBm						
Operating Temperature	-40 to +85	°C						
Storage Temperature	-65 to +150	°C						

Test Conditions

$V_S = +5V_{DC}$	TA = +25°C	LO Input = 0dBm, 400MHz			
IF Input F=400.1 MHz	GC1 = 0, GC2 = 0; 0dBm				
	GC1 = 1, GC2 = 0; -20dBm				
	GC1 = 1, GC2 = 1; -40dBm				

Product Specifications – IF Input (I/Q mixing to baseband)

Product Specifications – Stuck Mixer (DC on LO Port – gain controlled amplifier)

Parameters Test Conditions Unit Min. Typ.					(DC on LO Port – gain controlled ampliner)					
Test Conditions	Unit	Min.	Тур.	Max.	Parameters	Test Conditions	Unit	Min.	Тур.	Max.
	MHz	200	240-440	600	Frequency Range		MHz	200		600
50ohm reference	dB		20		Return Loss	50ohm reference	dB		20	
	dB		35		Gain		dB		40	
gain set=high	dBm		-30		Input P1dB	gain set=high	dBm		-26	
GC1=GC2=1	dBm		-20		Input IP3	GC1=GC2=1	dBm		-16	
	dB		6		Noise Figure	-	dB		6	
	dB		15		Gain		dB		20	
gain set=medium	dBm		-10		Input P1dB	gain set=medium	dBm		-6	
GC2=0	dBm		0		Input IP3	GC2=0	dBm		4	
	dB		10		Noise Figure		dB		9	
	dB		-5		Gain		dB		0	
gain set=low	dBm		10		Input P1dB	gain set=low	dBm		14	
ĞC1=GC2=0	dBm		20		Input IP3	ĞC1=GC2=0	dBm		24	
1	dB		30		Noise Figure		dB		30	
	Test Conditions 50ohm reference gain set=high GC1=GC2=1 gain set=medium GC1=1 GC2=0 gain set=low	MHz	Min. Min. Min. Min. Min. Min. 200	Test Conditions Unit Min. Typ. MHz 200 240-440 50ohm reference dB 20 dB 35 dBm -30 dBm -20 dB 6 dB 15 gain set=medium GC1=1 GC2=0 dBm -10 dB 10 dB 10 dB 10 dBm 20	Test Conditions Unit Min. Typ. Max. MHz 200 240-440 600 50ohm reference dB 20 20 dB 35 35 35 dBm -30 36 36 dBm -20 36 36 dBm -20 36 36 dBm -10 36 36 dBm -10 36 36 dBm 0 36 36 dBm 0 36 36 dBm 10 36 36 dBm 20 36 36	Test Conditions Unit Min. Typ. Max. Parameters 50ohm reference dB 20 Return Loss gain set=high GC1=GC2=1 dB 35 Gain dBm -30 Input P1dB dBm -20 Input IP3 dB 6 Noise Figure dB 15 Gain dBm -10 Input P1dB Input IP3 Input IP3 dB 10 Noise Figure dB -5 Gain dBm 10 Input IP3 dBm 20 Input IP3	Test Conditions Unit Min. Typ. Max. Parameters Test Conditions 500hm reference dB 20 Return Loss 500hm reference dB 35 Gain Input P1dB gain set=high GC1=GC2=1 dBm -30 Input IP3 GC1=GC2=1 dB 6 Noise Figure GC1=GC2=1 dB 15 Gain GC1=GC2=1 dBm -10 Input P1dB gain set=medium GC1=1 GC2=0 dB 10 Noise Figure dB -5 Gain Input IP3 GC2=0 dBm 10 Input P1dB gain set=low GC1=GC2=0 dBm 10 Input P1dB gain set=low GC1=GC2=0 dBm 20 Input IP3 GC1=GC2=0	Test Conditions Unit Min. Typ. Max. Parameters Test Conditions Unit 500hm reference dB 20 Return Loss 500hm reference dB gain set=high GC1=GC2=1 dB 35 Gain dB dB gain set=high GC1=GC2=1 dB 6 Input IP3 GC1=GC2=1 dB dB 15 Gain dB dB gain set=medium GC1=1 GC2=0 dB Input IP3 gain set=medium GC1=1 GC2=0 dBm dB 10 Noise Figure dBm dBm dB -5 Gain dB dB gain set=low GC1=GC2=0 dB dB Input IP3 gain set=low GC1=GC2=0 dB dBm 20 Input IP3 GC1=GC2=0 dB	Test Conditions Unit Min. Typ. Max. Parameters Test Conditions Unit Min. MHz 200 240-440 600 Frequency Range MHz 200 50ohm reference dB 20 Return Loss 50ohm reference dB dB 35 Gain dB dB dBm -30 Input P1dB gain set=high GC1=GC2=1 dBm dBm -20 Input IP3 GC1=GC2=1 dBm dBm 15 Gain gain set=medium GC1=1 dB dBm -10 Input P1dB gain set=medium GC1=1 dBm dB 10 Noise Figure dB dB dB -5 Gain dB dB gain set=low GC1=GC2=0 dBm Input P1dB gain set=low GC1=GC2=0 dBm dBm 20 Input IP3 GC1=GC2=0 dBm	Test Conditions

Product Specifications - I/Q Output

	" C Curpur				
Parameters	Additional Test Conditions	Unit	Min.	Тур.	Max.
I/Q Output Frequency Range		MHz	DC		500
I/Q Output Amplitude Balance		dB	-0.2		0.2
I/Q Output Phase Balance		deg	-2		2
I/Q Output Common-mode Volta	e	V		2.5	

Product Specifications – LO Input

Parameters	Additional Test Conditions	Unit	Min.	Тур.	Max.
LO Input Level		dBm	-3	0	+3
Return Loss		dB		20	

Product Specifications - Miscellaneous

Parameters	Additional Test Conditions	Unit	Min.	Тур.	Max.
Supply Voltage		V	+4.75	+5.0	+5.25
Supply Current		mA		180	
Thermal Resistance		°C		TBD	

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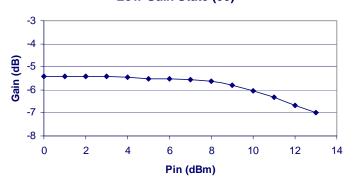
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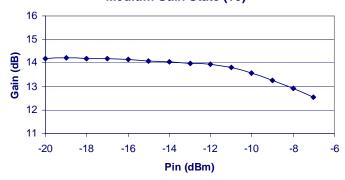


SRF-2016 SiGe IF Receiver

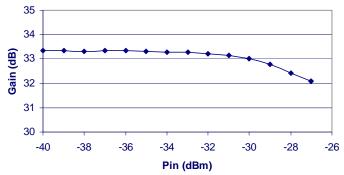
Gain vs. Pin Low Gain State (00)



Gain vs. Pin **Medium Gain State (10)**



Gain vs. Pin High Gain State (11)



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Advanced Data Sheet

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Pin Out Description

Pin#	Function	Description	Additional Comments
1	BBIN	Baseband I-axis output (-)	self-biasing
2	BBIP	Baseband I-axis output (+)	self-biasing
3	VCC	Positive power supply	
4	GC2	Gain control input, stage 2	5V CMOS levels
5	GC1	Gain control input, stage 1	5V CMOS levels
6	VEE	Ground	
7	VCC	Positive power supply	
8	INP	IF input (+)	self-biasing; AC-couple
9	INN	IF input (-)	self-biasing; AC-couple
10	VCC	Positive power supply	
11	VEE	Ground	
12	LON	LO input (-)	self-biasing; AC-couple
13	LOP	LO input (+)	self-biasing; AC-couple
14	VCC	Positive power supply	
15	BBQN	Baseband Q-axis output (-)	self-biasing
16	BBQP	Baseband Q-axis output (+)	self-biasing





Caution: ESD Sensitive

Appropriate precaution in handling, packaging and testing devices must be observed.

Advanced Data Sheet

SRF-2016 SiGe IF Receiver

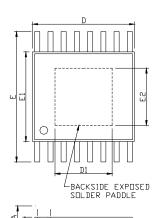
Part Number Ordering Information

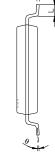
: u. : : : : : : : : : : : : : : : : : :									
Part Number	Reel Size	Devices/Reel							
SRF-2016	TBD	TBD							

Part Symbolization

The part will be symbolized with a "TBD" marking designator on the top surface of the package.

Package Dimensions





- NOTE

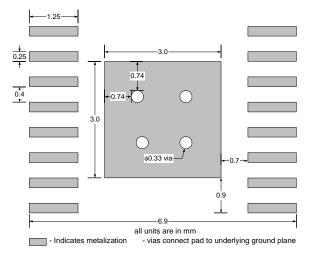
 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH
 PROTRUSIONS OR GATE BURRS

 2. TOLERANCE ±0.1 mm UNLESS OTHERWISE SPECIFIED

- 2. TOLLOWING J. HIM ON THE STREET OF T

SYMBOLS	DIMENS	IONS IN MILLI	METERS	DIMENSIONS IN INCHES			
3 I MBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
A			1.15			0.045	
A1	0.00		0.10	0.000		0.004	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
ь	0.19		0.30	0.007		0.012	
C	0.09		0.20	0.004		0.008	
D	4.90	5.00	5.10	0.193	0.197	0.201	
D1		2.80			0.110		
Е		6.40			0.252		
E1	4.30	4.40	4.50	0.169	0.173	0.177	
E2		2.80			0.110		
e		0.65			0.026		
L	0.45	0.60	0.75	0.018	0.024	0.030	
у			0.10			0.004	
θ	0°		8°	0°		8°	

Test PCB Pad Layout



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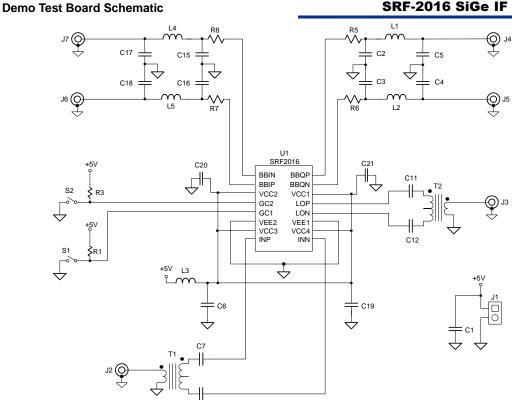
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Advanced Data Sheet

SRF-2016 SiGe IF Receiver



Bill of Materials

Dill of Materials					
Component Designator	Value	Qty	Vendor	Part Number	Description
U1		1	SMDI	SRF-2016	IF receiver
J1		1	Digikey-Sullins	S1312-02-ND	2 pin 0.1" power supply header
J2, J3, J4, J5, J6, J7		6	Johnson Components	142-0701-851	SMA end launch connector
T1, T2		2	Mini-Circuits	TC1-1	Transformer
C1	1uF	1	Venkel	C1206Y5V160-105ZNE	1206 size supply bypass capacitor
S1, S2		1	Grayhill	GH1102-ND	Dual DIP switch
R1, R3	1 kohm	2	Venkel	CR0603-16W-102JT	0603 size pull-up resistor
C6, C19, C20, C21	1nF	4	Venkel	C0603COG500-102JNE	0603 size bypass capacitor
L1, L2, L3, L4, L5	1uH	5	Panasonic	PCD1008TR-ND	1210 size inductor
C7, C8, C11, C12	18pF	4	Venkel	C0603COG500-180JNE	0603 size coupling capacitor
R5, R6, R7, R8	0 ohm	4	Venkel	CR1206-8W-000T	1206 size resistor
C2, C3, C4, C5, C15, C16, C17, C18	820pF	8	Venkel	C0603COG500-821JNE	0603 size filter capacitor

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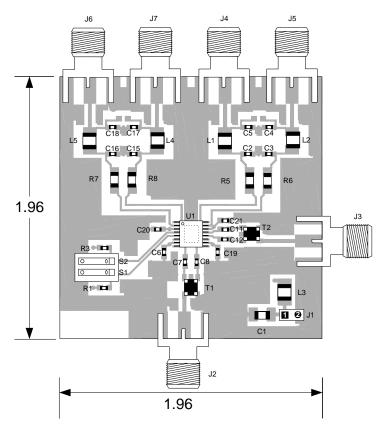
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Demo Test Board (Fully Assembled PCB)



Note: Dimensions in inches

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